

#### Features

- Collector Current Capability Ic=0.2A
- Collector Emitter Voltage VCEO=40V

#### Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)		
HMMBT3904WT1G	SOT-323	K2N	3000		

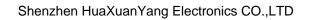
### Maxmim Ratings (Ta=25 unless otherwise noted)

Parameter	Symbol	Rating	Unit		
Collector - Base Voltage	Vсво	60			
Collector - Emitter Voltage	Vceo	40	V		
Emitter - Base Voltage	Vebo	5			
Collector Current - Continuous	lc	200	mA		
Collector Power Dissipation	Pc	200	mW		
Thermal Resistance From Junction To Ambient	Roja	625	°C/W		
Junction Temperature	TJ	150	°C		
Storage Temperature Range	Tstg	-55 to 150	C		

## Electrcal Charcteristics (Ta=25 unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Collector- base breakdown voltage	Vсво	Ic= 100 μA, IE= 0 (Note.1)	60			
Collector- emitter breakdown voltage	Vceo	Ic= 1 mA, I <sub>B</sub> = 0 (Note.1)	40			V
Emitter - base breakdown voltage	Vebo	IE= 100 µ A, IC= 0 (Note.1)	5			
Collector-base cut-off current	Ісво	VcB= 60 V , IE= 0 (Note.1)			60	
Collector- emitter cut-off current	ICEO	Vce= 40 V , Ie= 0 (Note.1)			700	nA
Collector- emitter cut-off current	ICEX	VCE= $30 \text{ V}$ , VBE(off)= $3 \text{ V}$			50	
Emitter cut-off current	Іево	VEB= 5V , IC=0			100	
Collector-emitter saturation voltage (Note.1)		Ic=10 mA, IB=1 mA			0.25	
Collector-emitter saturation voltage (Note.1)	VCE(sat)	Ic=50 mA, Iв=5 mA			0.3	V
Base - emitter saturation voltage (Note.1)	VBE(sat)	Ic=10 mA, IB=1 mA			0.85	v
Dase - emilier saturation voltage (Note. I)	VBE(sat)	Ic=50 mA, IB=5 mA			0.95	
	hFE(1)	Vce= 1V, Ic= 100 uA	40			
DC current gain (Note.1)	hFE(2)	Vce= 1V, lc= 1 mA 70				
De current gain (Note. 1)	hFE(3)	Vce= 1V, Ic= 10 mA	100		300	
	hFE(4)	Vce= 1V, Ic= 50 mA	60			
Delay time	td	td Vcc=3V, VBE(off)=0.5V Ic=10mA,			35	
Rise time	tr	IB1=1mA			35	nS
Storage time	ts	V(22-3)/ 10-10m ( 154-152-1m)			225	
Fall time	tf	Vcc=3V, Ic=10mA, IB1= IB2=1mA			75	
Collector input capacitance	Cib	VEB= 0.5V, IE= 0,f=1MHz			8	۳Ē
Collector output capacitance	Cob	Vcb= 5V, IE= 0,f=1MHz			4	pF
Transition frequency	f⊤	Vce= 20V, Ic= 10mA,f=100MHz	300			MHz

Note.1: Pulse test: pulse width  ${\leqslant}300\mu s$  duty cycle  ${\leqslant}$  2.0%.



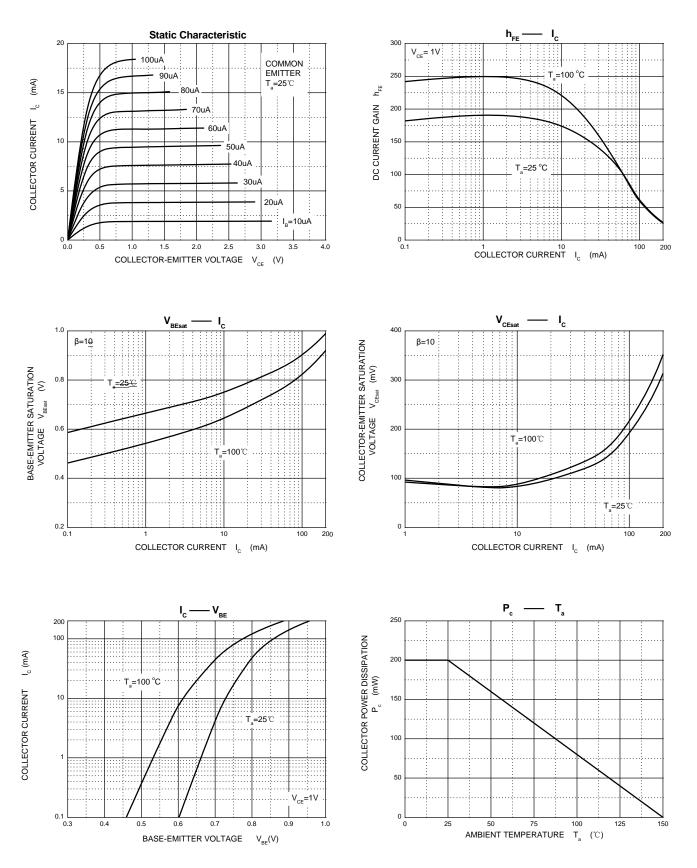


SOT-323

B

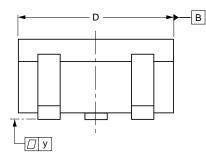


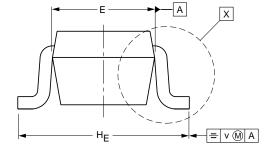
## **Typical Characteristics**

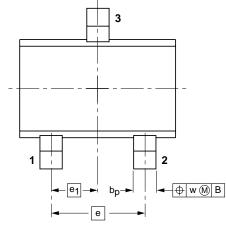


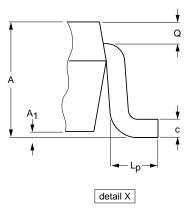


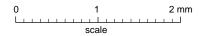
## SOT-323 Package Outline Dimensions











UNIT	A	A <sub>1</sub> max	<sup>b</sup> р	с	D	Е	е	e1	Η <sub>E</sub>	Lp	Q	v	w
mm	1.1 0.8	0.1	0.4 0.3	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2



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